

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Top Source)	4.3	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Bottom Drain)	1.6	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	42	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	105	°C/W
$R_{\theta JA}$ Thermal Resistance, Junction to Ambient		(Note 1i)	17	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1j)	26	
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1k)	12	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
7660DC	FDMC7660DC	Dual Cool TM Power 33	13"	12 mm	3000 units

FDMC7660DC N-Channel Dual CoolTM PowerTrench[®] MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, V_{GS} = 0 \ V$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		15		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V, V_{GS} = 0 V$			1	μA
I _{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = 20 V, V_{DS} = 0 V$			100	nA
On Chara	acteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1.2	2	2.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-7		mV/°C
		V _{GS} = 10 V, I _D = 22 A		1.6	2.2	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 4.5 V, I _D = 18 A		2.5	3.3	mΩ
		$V_{GS} = 10 V, I_D = 22 A, T_J = 125^{\circ}C$		2.2	3.3	
9 _{FS}	Forward Transconductance	$V_{DS} = 5 V, I_{D} = 22 A$		147		S
C _{iss} C _{oss} C _{rss}	Input Capacitance Output Capacitance Reverse Transfer Capacitance Output Depictment	V _{DS} = 15 V, V _{GS} = 0 V, f = 1MHz		3885 1215 100	5170 1620 150	pF pF pF
R _g Switching	Gate Resistance			0.7	1.5	Ω
t _{d(on)}	Turn-On Delay Time			17	31	ns
t _r	Rise Time	V _{DD} = 15 V, I _D = 22 A,		6.6	13	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		36	58	ns
t _f	Fall Time			5	10	ns
Q _q	Total Gate Charge	V _{GS} = 0 V to 10 V		54	76	nC
Q _q	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V V_{DD} = 15 V,$		24	34	nC
Q _{gs}	Gate to Source Charge	$I_D = 22 \text{ A}$		13		nC
Q _{gd}	Gate to Drain "Miller" Charge			5.5		nC
Drain-So	urce Diode Characteristics					
V _{SD}	Source-Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 22 A$ (Note 2)		0.8	1.2	V
	ç	$V_{GS} = 0 V, I_{S} = 1.9 A$ (Note 2)		0.7	1.2	-
t _{rr}	Reverse Recovery Time	I _F = 22 A, di/dt = 100 A/μs		43	69	ns
Q _{rr}	Reverse Recovery Charge			24	38	nC

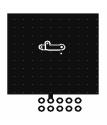
2

查询"FDMC7660DC"供应商 Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Top Source)	4.3	
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case	(Bottom Drain)	1.6	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1a)	42	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	105	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1c)	29	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1d)	40	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1e)	19	°C/M
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1f)	23	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1g)	30	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1h)	79	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1i)	17	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1j)	26	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1k)	12	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1I)	16	

NOTES:

1. R_{0JA} is determined with the device mounted on a FR-4 board using a specified pad of 2 oz copper as shown below. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



a. 42 °C/W when mounted on a 1 in² pad of 2 oz copper



b. 105 °C/W when mounted on a minimum pad of 2 oz copper

c. Still air, 20.9x10.4x12.7mm Aluminum Heat Sink, 1 in² pad of 2 oz copper

d. Still air, 20.9x10.4x12.7mm Aluminum Heat Sink, minimum pad of 2 oz copper

e. Still air, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, 1 in² pad of 2 oz copper

f. Still air, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, minimum pad of 2 oz copper

g. 200FPM Airflow, No Heat Sink,1 in² pad of 2 oz copper

h. 200FPM Airflow, No Heat Sink, minimum pad of 2 oz copper

i. 200FPM Airflow, 20.9x10.4x12.7mm Aluminum Heat Sink, 1 in² pad of 2 oz copper

j. 200FPM Airflow, 20.9x10.4x12.7mm Aluminum Heat Sink, minimum pad of 2 oz copper

k. 200FPM Airflow, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, 1 in² pad of 2 oz copper

I. 200FPM Airflow, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, minimum pad of 2 oz copper

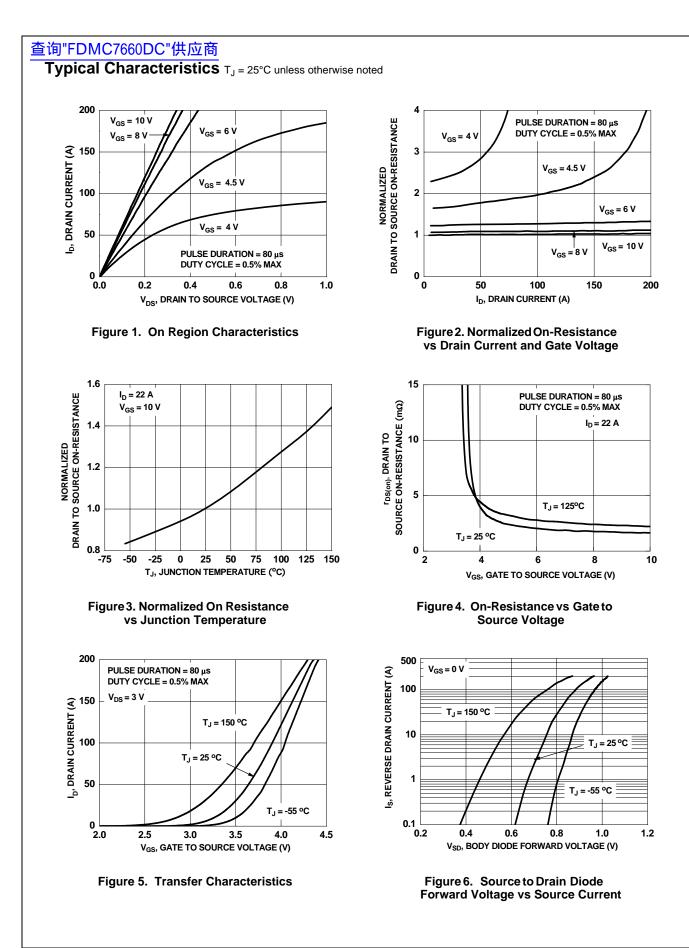
2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%.

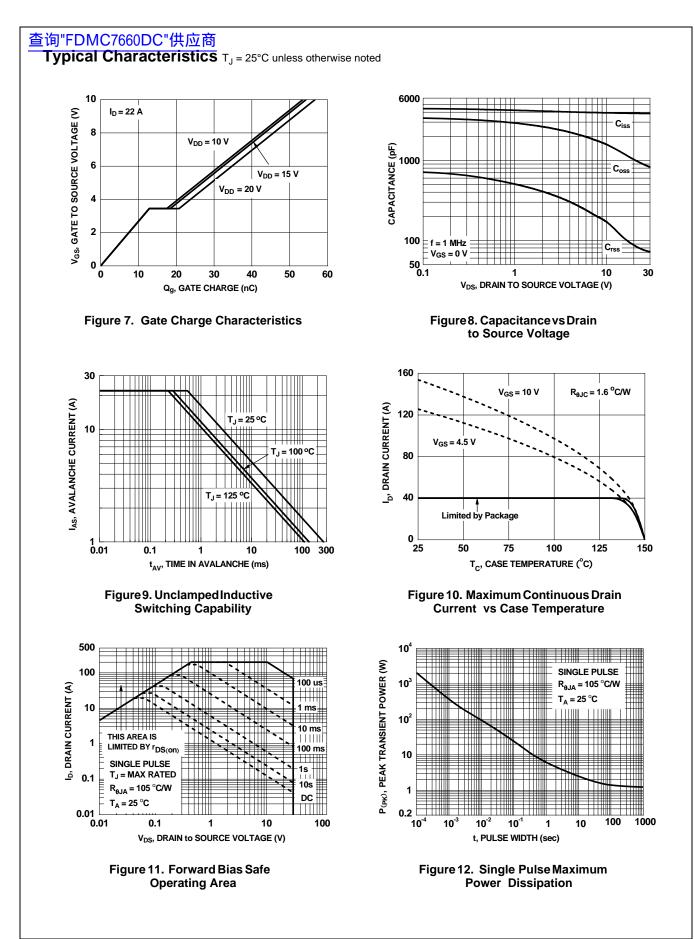
3. E_{AS} of 220 mJ is based on starting T_J = 25 $^{\circ}$ C; N-ch: L = 1 mH, I_{AS} = 21 A, V_{DD} = 27 V, V_{GS} = 10 V. 100% test at L = 0.3 mH, I_{AS} = 33.5 A.

4. As an N-ch device, the negative Vgs rating is for low duty cycle pulse ocurrence only. No continuous rating is implied.

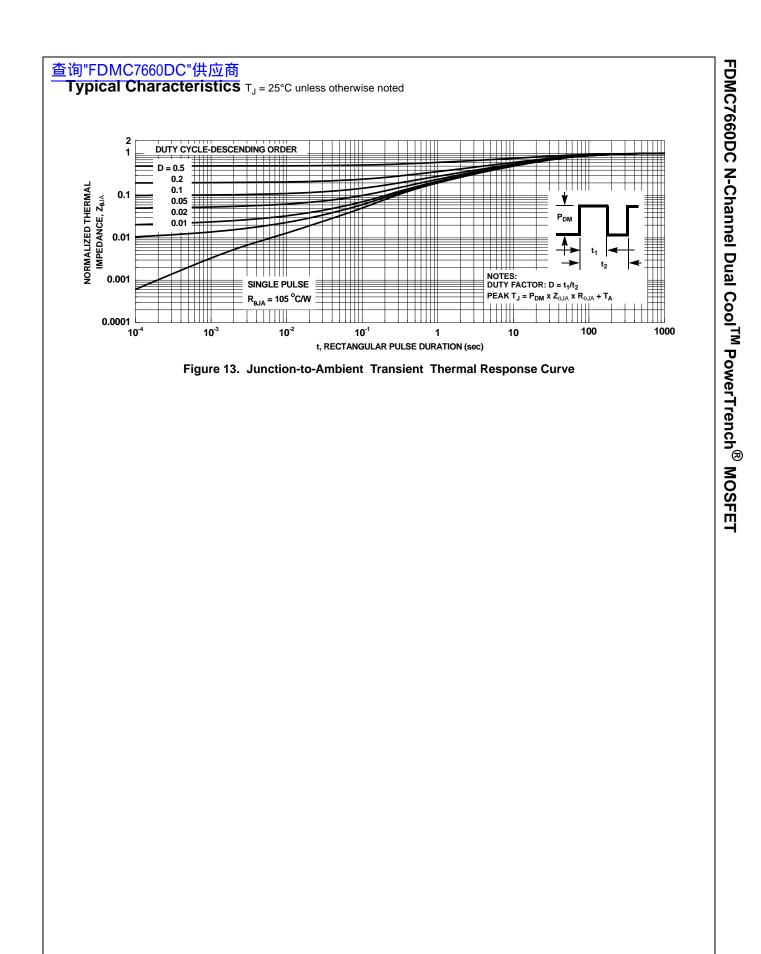
5. $I_{SD} \leq$ 22 A, di/dt \leq 100 A/µs, $V_{DD} \leq BV_{DSS},~$ Starting T_J = 25 °C.

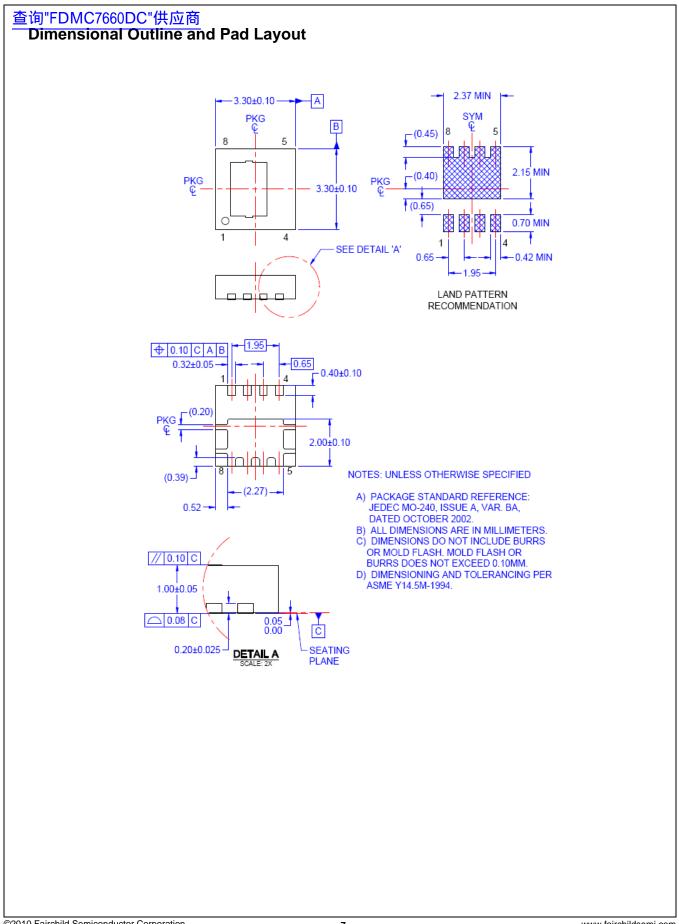






FDMC7660DC N-Channel Dual CoolTM PowerTrench[®] MOSFET





FAIRCHILD

SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks

AccuPower™	F-PFS™	Power-SPM™	SYSTEM ^{®*}
Auto-SPM™	FRFET [®]	PowerTrench [®]	GENERAL
Build it Now™	Global Power Resource SM	PowerXS™	The Power Franchise [®]
CorePLUS™	Green FPS™	Programmable Active Droop™	the ®
CorePOWER™	Green FPS™ e-Series™	QFET®	puwer
CROSSVOLT™	G <i>max</i> ™	QS™	franchise TinyBoost™
CTL™	GTO™	Quiet Series [™]	TinyBuck™
Current Transfer Logic™	IntelliMAX™	RapidConfigure™	TinyCalc™
DEUXPEED®	ISOPLANAR™		TinyLogic®
Dual Cool™	MegaBuck™		TINYOPTO™
EcoSPARK [®]	MICROCOUPLER™	Saving our world, 1mW/W/kW at a time™	TinyPower™
EfficentMax™	MicroFET™	SignalWise™	TinyPWM™
ESBC™	MicroPak™	SmartMax™	TinyWire™
R	MicroPak2 [™]	SMART START™	TriFault Detect™
T	MillerDrive™	SPM®	TRUECURRENT™*
Fairchild [®]	MotionMax™	STEALTH™	μSerDes™
Fairchild Semiconductor [®]	Motion-SPM [™]	SuperFET™	
FACT Quiet Series™	OptiHiT™ optice optice®	SuperSOT™-3	SerDes
FACT	OPTOLOGIC®	SuperSOT™-6	UHC®
FAST®		SuperSOT™-8	Ultra FRFET™
FastvCore™		SupreMOS™	UniFET™
FETBench™	U.	SyncFET™	VCX™
FlashWriter [®] *	PDP SPM™	Sync-Lock™	VisualMax™
FPS™			XS™
*Trademarks of System General Cor	poration, used under license by Fairchild	Semiconductor.	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN: NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS. NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are 1. intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or 2. system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary First Production		Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.